

Monolithic Amplifier ERA-33SM+

500 DC to 3 GHz

FEATURES

- DC to 3 GHz
- Single Voltage Supply
- Internally Matched to 50Ω
- Unconditionally Stable
- Low Performance Variation Over Temperature
- Transient Protected
- Aqueous Washable
- Protected By US Patent 6,943,629



Generic photo used for illustration purposes only

CASE STYLE: WW107

+RoHS Compliant The +Suffix identifies RoHS Compliance. ur website for methodologies and qualific

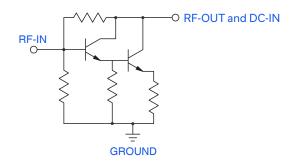
APPLICATIONS

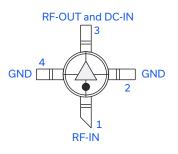
- · Cellular/ PCS/ 3G Base Station
- CATV, Cable Modem & DBS
- Fixed Wireless & WLAN
- · Microwave Radio & Test Equipment

PRODUCT OVERVIEW

ERA-33SM+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in a Micro-X package. ERA-33SM+ uses Darlington configuration and is fabricated using InGaP HBT technology. Expected MTTF is 5,250 years at +85°C case temperature.

SIMPLIFIED SCHEMATIC AND PIN DESCRIPTION





Function	Pin Number	Description
RF-IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.

REV. Q ECO-024491 ERA-33SM+ MCL NY 250211





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ELECTRICAL SPECIFICATIONS AT +25°C AND 40 mA UNLESS NOTED OTHERWISE

Parameter	Condition (GHz)	Min.	Тур.	Max.	Units	Cpk
Frequency Range ¹		DC		3	GHz	
	0.1	18.7	19.3	20.6		
	1.0		18.7		dB	. 4 =
Gain	2.0	15	17.4	18.5		≥ 1.5
	3.0	14.2	15.9	17.3		
	0.1		0.0021	.004		
Magnitude of Gain Variation vs. Temperature	1.0		0.0029	.005	dB/°C	
(Values Are Negative)	2.0		0.0035	.007		
	3.0		0.004	.008		
	0.1		35			
Local Balance Local	1.0		25			
Input Return Loss	2.0		26		dB	
	3.0		28			
	0.1		35			
0.1.15.1.1	1.0		22		dB	
Output Return Loss	2.0		20			
	3.0		20			
Reverse Isolation	1.0	19	22.5		dB	
	0.1		+14.3		dBm	
0.1.15	1.0		+16.6			4.00
Output Power @ 1 dB Compression	2.0	+11.5	+13.5			≥ 1.33
	3.0		+13.9			
	0.1		+15.5			
Saturated Output Power	1.0		+15.5		alD.co	
(at 3 dB Compression)	2.0		+15		dBm	
	3.0		+15			
	0.1	+27	+29.5		dBm	
0.1102	1.0		+30			. 4.22
Output IP3	2.0	+27.5	+30.3			≥ 1.33
	3.0	+27	+30			
	0.1		3.2	4.0	dB	
Naiss Figure	1.0		3.3	4.0		. 1 22
Noise Figure	2.0		3.3	4.1		≥ 1.33
	3.0		3.4	4.2		
Group Delay	2.0		82		psec	
Recommended Device Operating Current			40		mA	
Device Operating Voltage		+3.9	+4.3	+4.6	V	≥ 1.5
Device Voltage Variation vs. Temperature at 40 mA			-2.9		mV/°C	
Device Voltage Variation vs. Current at +25°C			3.8		mV/mA	
Thermal Resistance, Junction-to-Case ²			140		°C/W	

^{1.} Guaranteed specification DC-3 GHz. Low frequency cut off determined by external coupling capacitors.

ABSOLUTE MAXIMUM RATINGS

Parameter	Ratings		
Operating Temperature ⁴	-45°C to +85°C		
Storage Temperature	-65°C to +150°C		
Operating Current	75 mA		
Power Dissipation	330 mW		
Input Power	+13 dBm		

Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.

^{4.} Based on typical case temperature rise $+5^{\circ}\text{C}$ above ambient.



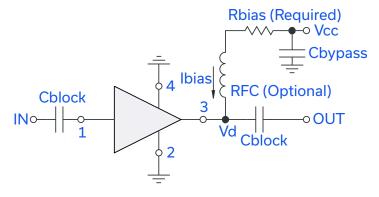
^{2.} Case is defined as ground leads.



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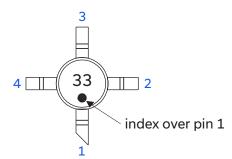
RECOMMENDED APPLICATION CIRCUIT



Test Board includes case, connectors, and components (in bold) soldered to PCB

R BIAS			
Vcc	"1%" Res. Values (Ohms) for Optimum Biasing		
7	69.8		
8	93.1		
9	115		
10	140		
11	165		
12	191		
13	215		
14	243		
15	267		
16	287		
17	316		
18	340		
19	365		
20	392		

PRODUCT MARKING



Markings in addition to model number designation may appear for internal quality control purposes.



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ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASHBOARD.

CLICK HER	

	Data Table
Performance Data & Graphs	Swept Graphs
	S-Parameter (S2P Files) Data Set (.zip file)
Case Style	WW107 Plastic micro-x package, lead finish: Matte-tin
Tape & Reel Standard Quantities Available on Reel	F4 7" Reels with 20, 50, 100, 200, 500 or 1K devices
Suggested Layout for PCB Design	PL075
Evaluation Board	TB-408-33+
Environmental Ratings	ENV08T2

ESD RATING

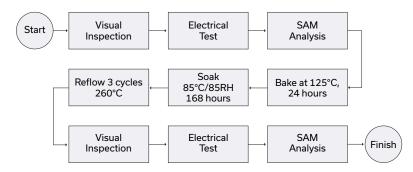
Human Body Model (HBM): Class 1B (500 V to < 1000 V) in accordance with ANSI/ESD STM 5.1 - 2001 Machine Model (MM): Class M1 (< 100 V) in accordance with ANSI/ESD STM 5.2 - 1999

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020C

No.	Test Required	Condition	Standard	Quantity
1	Visual Inspection	Low Power Microscope Magnification 40x	MIP-IN-0003 (MCT spec)	45 units
2	Electrical Test	Room Temperature	SCD (MCL spec)	45 units
3	SAM Analysis	Less than 10% growth in term of delamination	J-Std-020C (Jedec Standard)	45 units
4	Moisture Sensitivity Level 1	Bake at 125°C for 24 hours Soak at 85°C/85%RH for 168 hours Reflow 3 cycles at 260°C peak	J-Std-020C (Jedec Standard)	45 units

MSL TEST FLOW CHART



- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/terms/viewterm.html